SEMICONDUCTOR TECHNICAL DATA

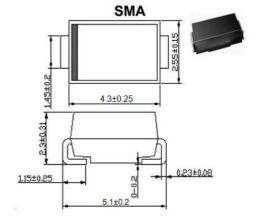
S3AA~S3MA

3A GLASS PASSIVATED SURFACE MOUNT RECTIFIER

Reverse Voltage 50 to 1000 Volts Forward Current 3.0 Amperes

Features

- Glass passivated junction
- Low forward voltage drop
- High current capability
- Low reverse leakage
- High surge current capability
- High reliablity
- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- AEC-Q101 qualified



Mechanical Data

- Case: SMA molded plastic body
- Terminals: Plated axial leads, solderable per MIL-STD-750, method 2026
- Polarity: Color band denotes cathode end
- Mounting Position: Any
- Weight: 0.065 grams (approximate)

Maximum Ratings and Electrical Characteristics

PARAMETER	SYMBOL	S3A	S3B	S3D	S3G	S3J	S3K	S3M	UNITS
Maximum repetitive peak reverse voltage	V RRM	50	100	200	400	600	800	1000	V
Maximum RMS voltage	V _{RMS}	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	V _{DC}	50	100	200	400	600	800	1000	V
Average Rectified Output Current 0.375" (9.5mm) lead length	I _o	3.0							А
Peak forward surge current, 8.3 mS single half sine-wave superimposed on rated load	I _{FSM}	90							А
Maximum instantaneous forward voltage at I 。	V _F	1.1							V
Maximum DC reverse current @ $T_J = 25^{\circ}C$ at rated DC blocking voltage @ $T_J = 125^{\circ}C$	I _R	5.0 200							μА
Typical junction capacitance (Note 1)	C _j	50							pF
Typical thermal resistance (Note 2)	R _{«JA}	70							°C/W
Operating junction temperature range	Тл	-55 to +150							$^{\circ}$ C
Storage temperature range	T _{STG}	-55 to +150							°C

Notes:

- 1. Measured at 1 MHz and applied reverse voltage of 4.0 VDC.
- 2. Thermal Resistance from Junction to Ambient 0.375"(9.5mm) lead length.



Ratings and Characteristic Curves

(T_A=25°C unless otherwise noted)

Fig.1- Forward Current Derating Curve

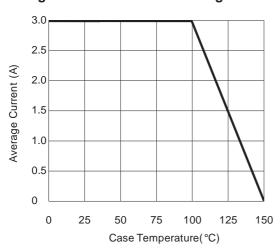


Fig.2- Surge Current Derating Curve

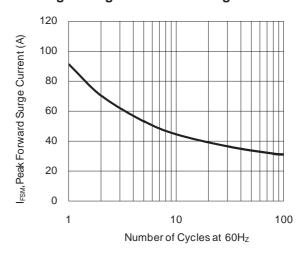


Fig.3- Typical Forward Voltage Characteristic

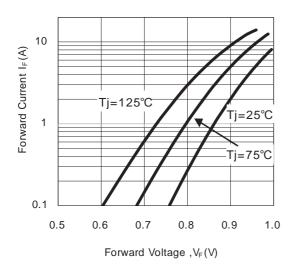


Fig.4- Typical Reverse Characteristic

